





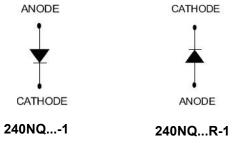
## 240NQ035(R)-1/240NQ040(R)-1/240NQ045(R)-1 SCHOTTKY RECTIFIER



#### **Features**

- 150℃ T<sub>J</sub> operation
- Unique high power, Half-Pak module
- Replaces three parallel DO-5'S
- Easier to mount and lower profile than DO-5' S
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Base plate: Nickel plated; Terminals: Nickel plated
- This is a Pb Free Device
- . All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Circuit Diagram**



## **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

The top side is terminal, the bottom side is base plate.

### Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.		Units
Peak Repetitive Reverse Voltage	$V_{RRM}$	-	35	240NQ035(R)-1	
Working Peak Reverse Voltage	$V_{RWM}$		40 240NQ040(R)-1		V
DC Blocking Voltage	$V_R$		45	240NQ045(R)-1	
Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle @Tc =96°C, rectangular wave form	240		А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	4080		Α
Non-Repetitive Avalanche Energy	E <sub>AS</sub>	T <sub>J</sub> =25℃,I <sub>AS</sub> =48A,L=0.28 mH	324		mJ
Repetitive Avalanche Current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ sec Frequency limited by $T_J$ max. $V_A$ =1.5 $\times$ V $_R$ typical	48		А

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## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V	@ 240A, Pulse, T <sub>J</sub> = 25 °C	0.59	0.61	V
	V <sub>F1</sub>	@ 480A, Pulse, T <sub>J</sub> = 25 °C	0.74	0.81	\ \ \
	V <sub>F2</sub>	@ 240A, Pulse, T <sub>J</sub> = 125 °C	0.55	0.58	V
	V F2	@ 480A, Pulse, T <sub>J</sub> = 125 °C	0.68	0.74	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 25 °C	0.6	20	mA
	$I_{R2}$	$@V_R = \text{rated } V_R T_J = 125 ^{\circ}\text{C}$	132	800	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	8670	10300	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

 $<sup>^{\</sup>star}\,$  Pulse width < 300  $\mu s,\,$  duty cycle < 2%

## **Thermal-Mechanical Specifications:**

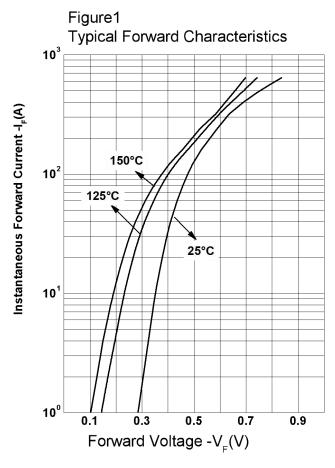
Characteristics	Symbol	Condition	Specific	Units	
Junction Temperature	TJ	-	-55 to +150		°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150		°C
Typical Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	0.25		°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.07		°C/W
Mounting Torque	Тм	Non-lubricated threads	Mounting Torque Terminal Torque	23(min) 29(max) 35(min) 46(max)	Kg-cm
Approximate Weight	wt	-	36		g
Case Style	PRM1-1				

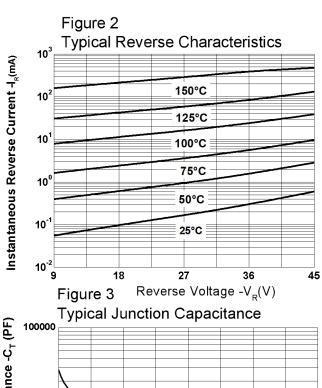


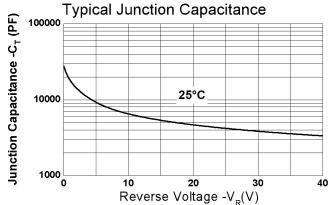




## **Ratings and Characteristics Curves**







### **Ordering Information**

Device	Package	Shipping		
240NQ1	PRM1-1(Pb-Free)	27pcs/ box		

## **Marking Diagram**

SS XXXX 240NQ035-1 Where XXXX is YYWW

1st row SS YYWW
2nd row 240NQ035-1
SS = SS
YY = Year
WW = Week

Cautions: Molding resin

Epoxy resin UL:94V-0

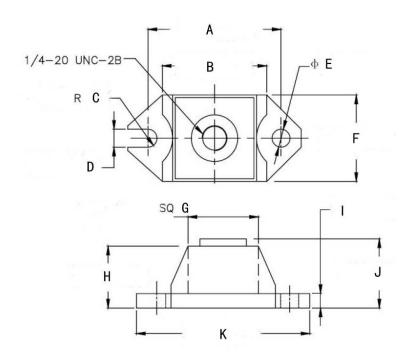
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# **Mechanical Dimensions PRM1-1 (Inches/Millimeters)**



SYMBOL	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
Α	29.35	30.95	1.155	1.219	
В	24.77	26.04	0.975	1.026	
С	1.79	2.19	0.070	0.087	
D	3.73	4.24	0.146	0.167	
Е	3.73	4.24	0.146	0.167	
F	18.42	19.69	0.725	0.775	
G	18.55	19.55	0.730	0.770	
Н	13.59	14.47	0.535	70.500	
I	3.05	3.90	0.120	0.154	
J	14.87	15.87	0.585	0.625	
К	38.61	39.62	1.520	1.560	







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